



- 1 -

Docket: 0756-1626

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Divisional Patent Application of )  
Shunpei YAMAZAKI et al. )  
Based On Serial No. 08/213,837 ) Art Unit: 2503  
Which Was Filed: March 16, 1994 ) Examiner: T. Arroyo  
For: SEMICONDUCTOR DEVICE AND )  
METHOD FOR FORMING THE )  
SAME ) Date: January 24, 1997

PRELIMINARY AMENDMENT

Honorable Assistant Commissioner for Patents  
Washington, D.C. 20231

Sir:

Please preliminarily amend the subject application as follows:

IN THE CLAIMS:

Cancel claim 1 and add new claims 21-33 as follows:

AJ

--21. An insulated gate field effect semiconductor device comprising:  
source and drain semiconductor regions and a channel  
semiconductor region in contact with said source and drain regions; and